

H.A

Notice of Allowability	Application No.	Applicant(s)	
	10/711,018	LIU, HONG-DA	
	Examiner Nguyen T. Ha	Art Unit 2831	

-- The MAILING DATE of this communication appears on the cover sheet with the correspondence address--

All claims being allowable, PROSECUTION ON THE MERITS IS (OR REMAINS) CLOSED in this application. If not included herewith (or previously mailed), a Notice of Allowance (PTOL-85) or other appropriate communication will be mailed in due course. THIS NOTICE OF ALLOWABILITY IS NOT A GRANT OF PATENT RIGHTS. This application is subject to withdrawal from issue at the initiative of the Office or upon petition by the applicant. See 37 CFR 1.313 and MPEP 1308.

1. This communication is responsive to 1/28/2005.
2. The allowed claim(s) is/are 1-9 and 22-29.
3. The drawings filed on 18 August 2004 are accepted by the Examiner.
4. Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).
 - a) All
 - b) Some*
 - c) None
 of the:
 1. Certified copies of the priority documents have been received.
 2. Certified copies of the priority documents have been received in Application No. _____.
 3. Copies of the certified copies of the priority documents have been received in this national stage application from the International Bureau (PCT Rule 17.2(a)).

* Certified copies not received: _____.

Applicant has THREE MONTHS FROM THE "MAILING DATE" of this communication to file a reply complying with the requirements noted below. Failure to timely comply will result in ABANDONMENT of this application.
THIS THREE-MONTH PERIOD IS NOT EXTENDABLE.

5. A SUBSTITUTE OATH OR DECLARATION must be submitted. Note the attached EXAMINER'S AMENDMENT or NOTICE OF INFORMAL PATENT APPLICATION (PTO-152) which gives reason(s) why the oath or declaration is deficient.
6. CORRECTED DRAWINGS (as "replacement sheets") must be submitted.
 - (a) including changes required by the Notice of Draftsperson's Patent Drawing Review (PTO-948) attached
 - 1) hereto or 2) to Paper No./Mail Date _____.
 - (b) including changes required by the attached Examiner's Amendment / Comment or in the Office action of Paper No./Mail Date _____.

Identifying indicia such as the application number (see 37 CFR 1.84(c)) should be written on the drawings in the front (not the back) of each sheet. Replacement sheet(s) should be labeled as such in the header according to 37 CFR 1.121(d).
7. DEPOSIT OF and/or INFORMATION about the deposit of BIOLOGICAL MATERIAL must be submitted. Note the attached Examiner's comment regarding REQUIREMENT FOR THE DEPOSIT OF BIOLOGICAL MATERIAL.

Attachment(s)

1. Notice of References Cited (PTO-892)
2. Notice of Draftsperson's Patent Drawing Review (PTO-948)
3. Information Disclosure Statements (PTO-1449 or PTO/SB/08),
Paper No./Mail Date _____.
4. Examiner's Comment Regarding Requirement for Deposit
of Biological Material
5. Notice of Informal Patent Application (PTO-152)
6. Interview Summary (PTO-413),
Paper No./Mail Date _____.
7. Examiner's Amendment/Comment
8. Examiner's Statement of Reasons for Allowance
9. Other _____.

DETAILED ACTION

EXAMINER'S AMENDMENT

1. An examiner's amendment to the record appears below. Should the changes and/or additions be unacceptable to applicant, an amendment may be filed as provided by 37 CFR 1.312. To ensure consideration of such an amendment, it MUST be submitted no later than the payment of the issue fee.

The application has been amended as follows:

Claims 10-21 are canceled based on the non-elected.

Allowable Subject Matter

2. Claims 1-9 and 22-29 are allowed.

The following is an examiner's statement of reasons for allowance:

With respect to claims 1-9, the prior art alone or in combination does not teach the limitation of a storage capacitor having a scattering effect adapted for use in a thin film transistor array loop, the storage capacitor comprising: a rough layer positioned above the first electrode, the rough layer comprising a medium layer and a passivation layer, and a second electrode, positioned above the rough layer, for implementing the scattering effect toward an external light source.

With respect to claims 22-24, the prior art alone or in combination does not teach the limitation of a storage capacitor having a scattering effect adapted for use in a thin film transistor array loop, the storage comprising: a second conductive layer, a rough layer, and a reflective layer with high reflectivity, the rough layer being positioned above the second conductive layer and comprise a medium layer and a passivation layer,

HR3|1505

wherein the passivation layer being positioned above the medium layer, the reflective layer being positioned above the rough layer.

With respect to claims 25-29, the prior art alone or in combination does not teach the limitation of a storage capacitor having a scattering effect adapted for use in a thin film transistor array loop, the storage capacitor comprising: a rough layer and a first conductive layer, the rough layer comprising a medium layer and a passivation layer, the medium layer being positioned above the passivation layer, the first conductive layer being positioned above the rough layer.

Any comments considered necessary by applicant must be submitted no later than the payment of the issue fee and, to avoid processing delays, should preferably accompany the issue fee. Such submissions should be clearly labeled "Comments on Statement of Reasons for Allowance."

Citation Relevant of Prior Art

3. The prior art made of record and not relied upon is considered pertinent to applicant's disclosure.

- a. Galvagni et al. (US 6,757,152) disclose cascade capacitor.
- b. Chen (US 6,466,427) discloses microelectronic capacitor structure compatible with copper containing microelectronic conductor layer processing.
- c. KarRoy et al. (US 6,459,562) disclose high density metal insulator metal capacitors.
- d. Liu (US 6,324,048) disclose ultra-small capacitor array.
- e. Mihara (US 5,471,363) disclose ferroelectric capacitive element.

f. Embree (US 5,187,637) discloses monolithic high-voltage capacitor.

Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Nguyen T. Ha whose telephone number is 571-272-1974. The examiner can normally be reached on Monday-Friday from 8:30AM to 6:00PM.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Dean Reichard can be reached on 571-272-2800 ext. 31. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see <http://pair-direct.uspto.gov>. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Nguyen T. Ha
March 9, 2005

Dean A. Reichard 3/15/05
DEAN A. REICHARD
SUPERVISORY PATENT EXAMINER
TECHNOLOGY CENTER 2800